

SuperCDMS HVeV Detector Characterization

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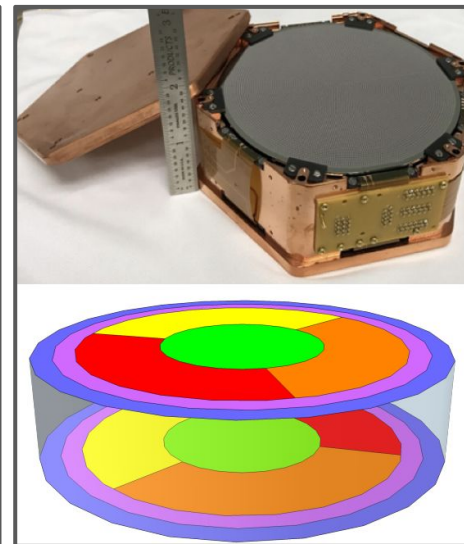
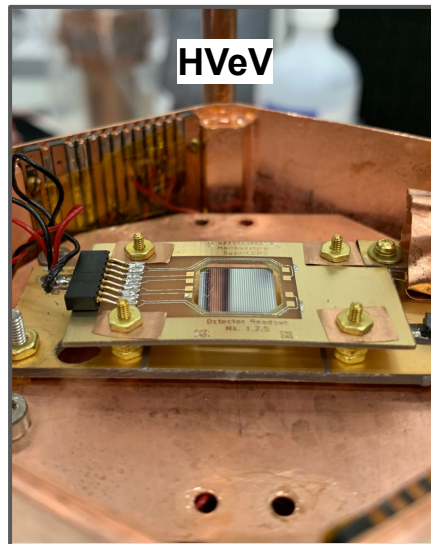


TRIUMF

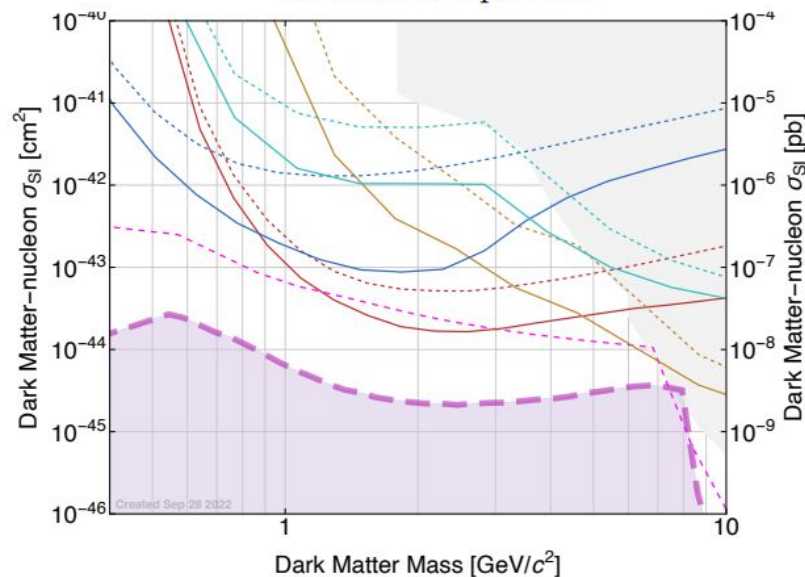


Super Cryogenic Dark Matter Search (SuperCDMS) Assumptions and Hopes

- Dark matter may interact with regular matter weakly
- Can interact with the bulk of the detector through electron or nuclear recoil
- With low/controlled background environment, this interaction can be measured.
- In SuperCDMS, one detector type is the **HV** detector
- Cryogenic Ge and Si crystals to measure phonons via QETs
- Large HV detectors for sufficient exposure and small HVeV with better resolution

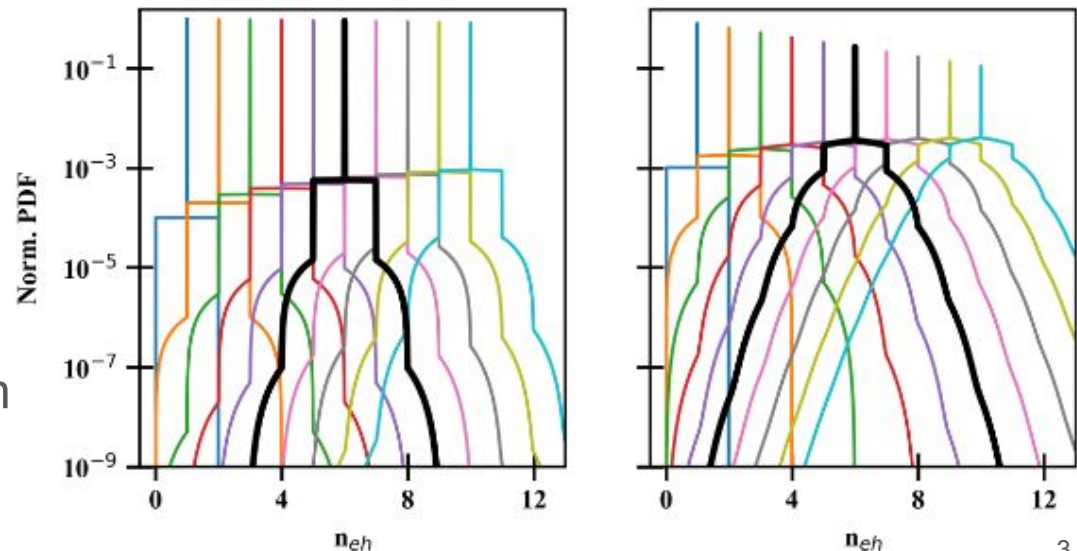
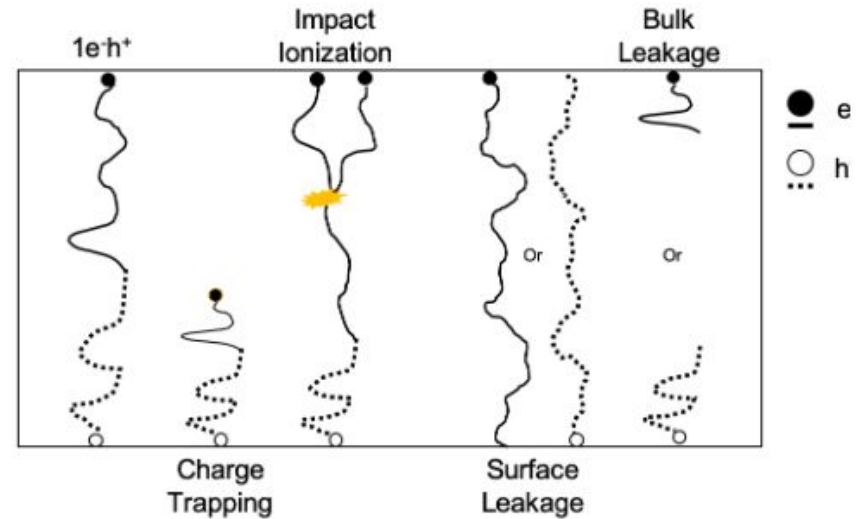


OI-PLR comparison

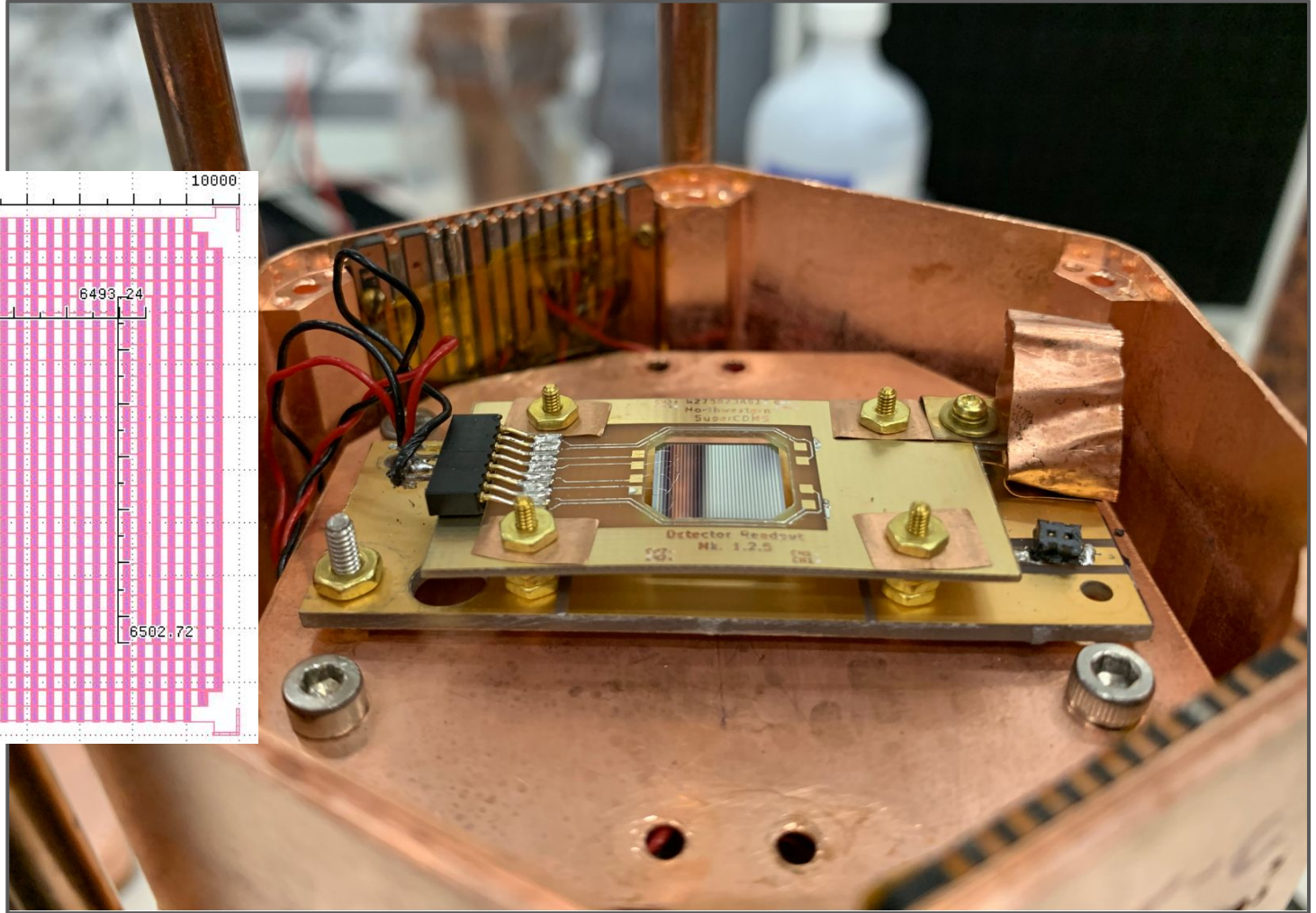


HVeV Detectors and NTL Effect

- **High-purity Si or Ge lattice**
- **High bias voltage (100-200V)**
- **NTL amplification**
 - e/h pairs drift across lattice and produce phonons
 - Measured energy quantized by phonon-mediated amplification of charge carriers
- **Additional crystal effects**
 - Charge trapping
 - Impact ionization
- **Background**
 - Random coincidence from external backgrounds



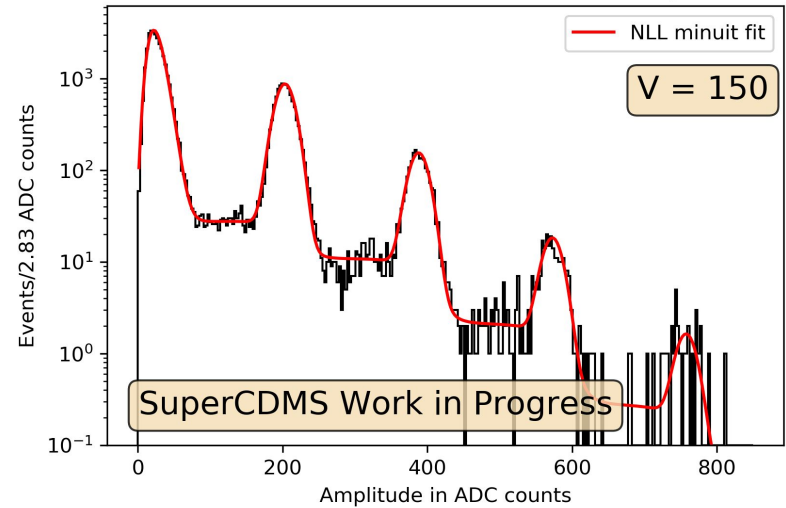
HVeV NF-C Detector at TRIUMF



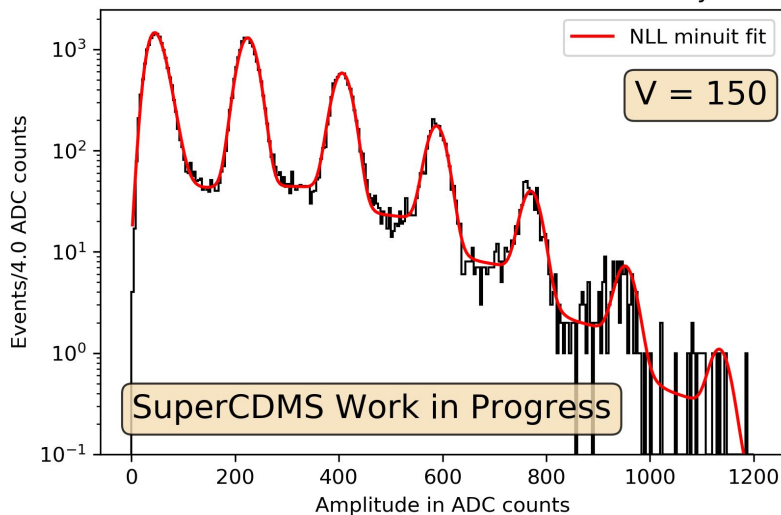
HVeV Calibration Data from TRIUMF

- Calibration using UV LED (~ 4 eV) at different intensities
- Shone towards center of detector
- 2 channels (inner and outer)
- Model fit on aggregate of both channels for total phonon signal

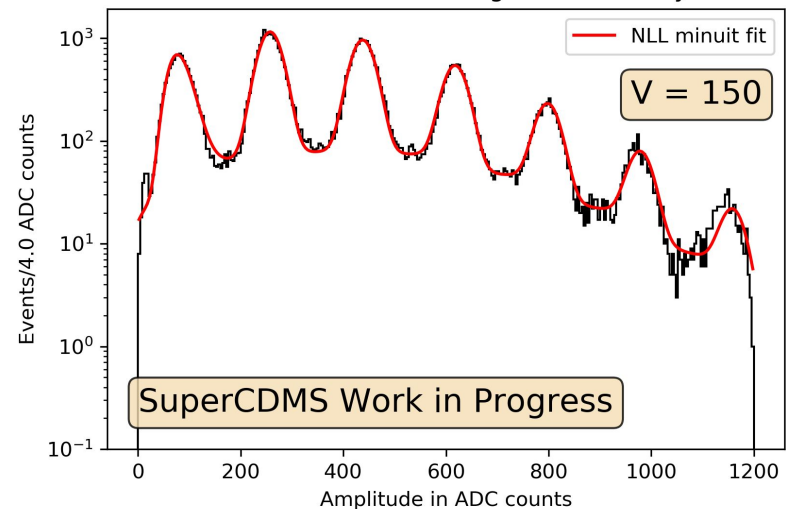
HVeV data and fit for low LED intensity



HVeV data and fit for medium LED intensity



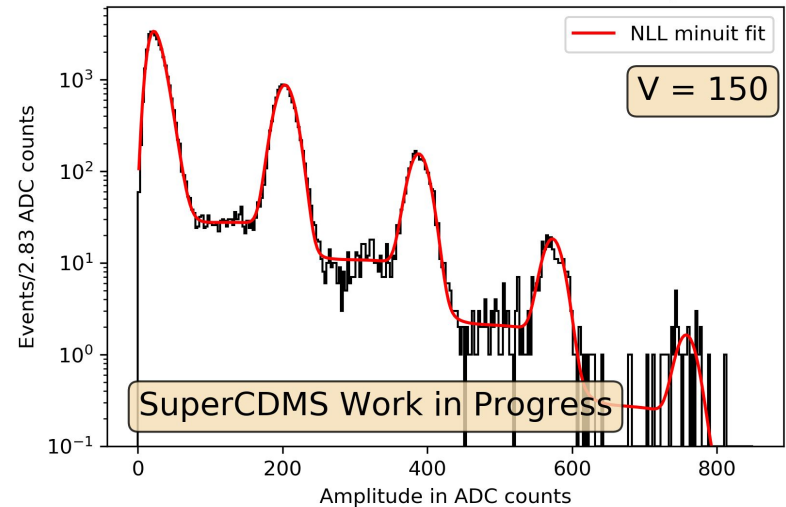
HVeV data and fit for high LED intensity



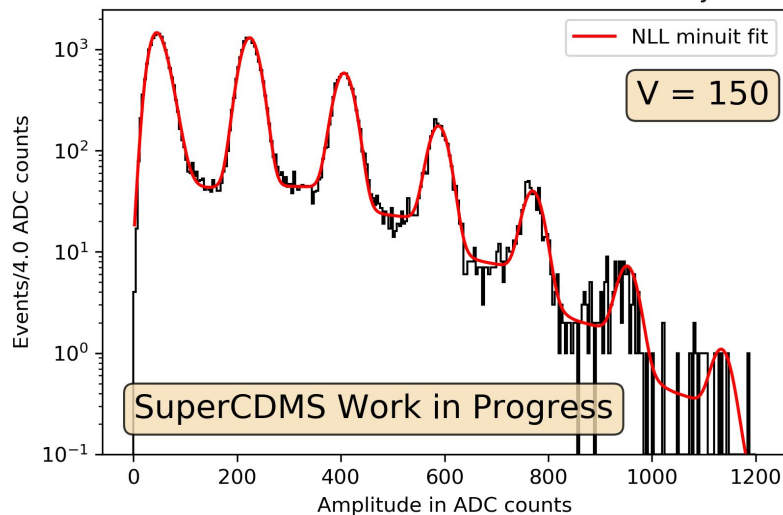
Fit Results for Different LED Intensities

- Fit for Poisson lambda (LED intensity), detector resolution (width of peaks), charge trapping and impact ionization, background, etc.
- **Puzzle: detector resolution and peak positions change with LED intensity?**

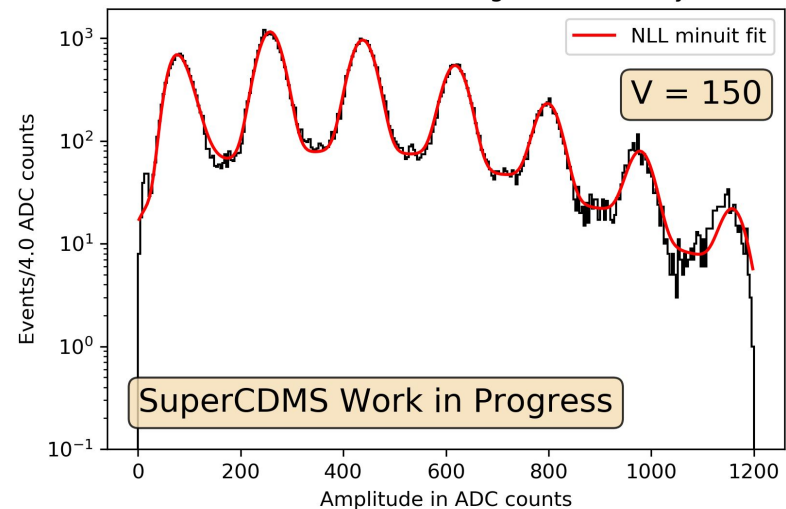
HVeV data and fit for low LED intensity



HVeV data and fit for medium LED intensity

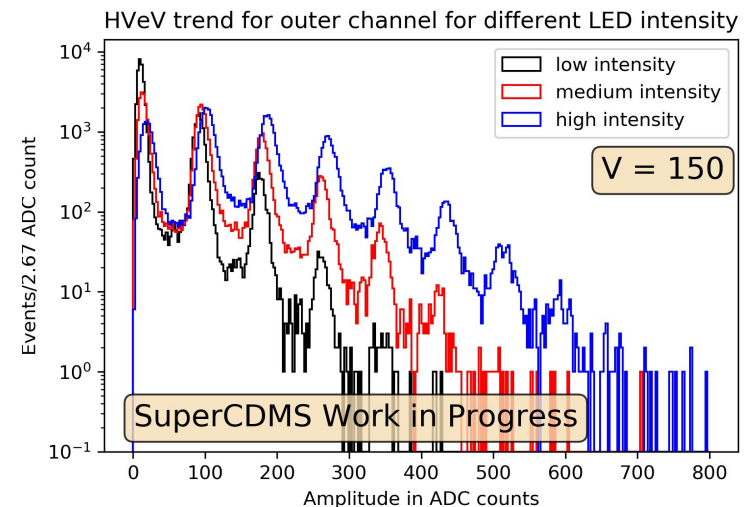
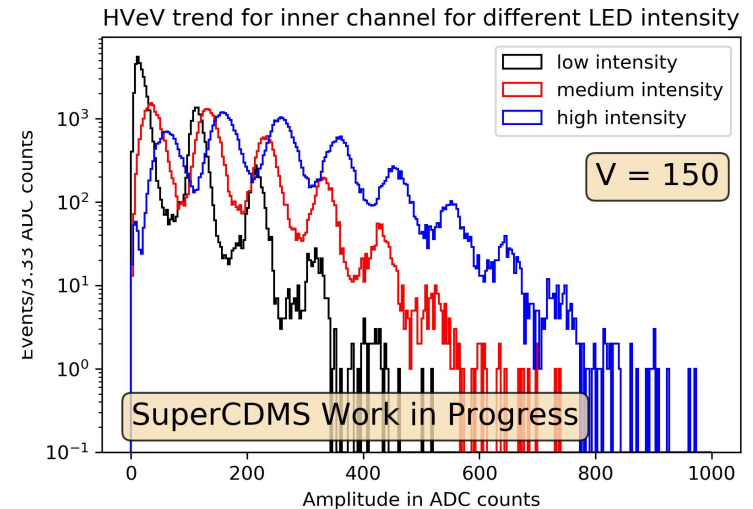


HVeV data and fit for high LED intensity



Inner Channel vs. Outer Channel Spectra

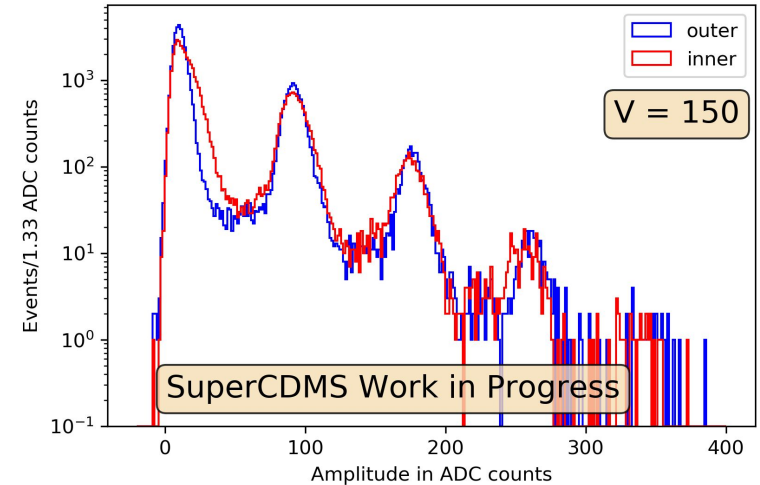
- LED is collimated on the center of detector (inner channel).
- More photons are hitting inner channel vs. outer channel.
- Peak positions variation is more pronounced for inner channel.
- Peak width (detector resolution) also varies!
- Phenomenon is based on # photons hitting detector.



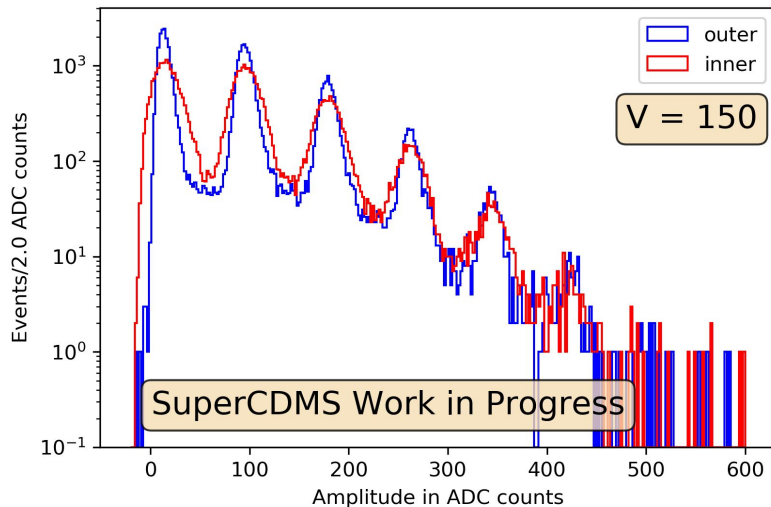
Inner Channel vs. Outer Channel Spectra

- Clear variation in peak widths
- Worse resolution for higher LED intensities
- What is going on here?

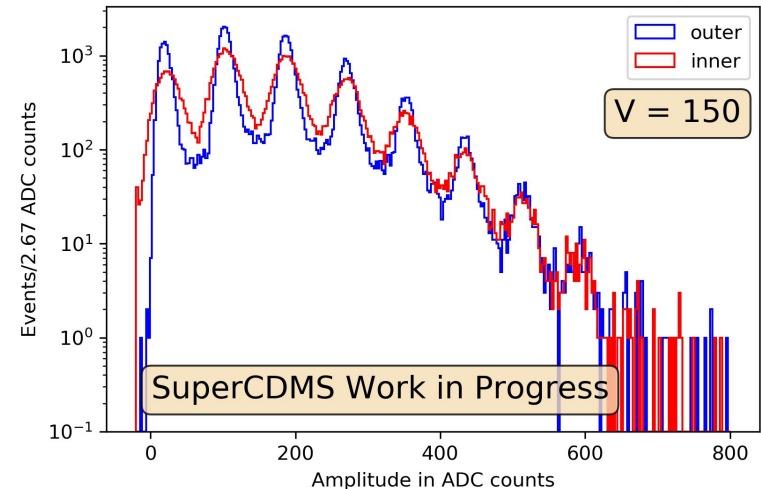
HV_{eV} difference between inner and outer channel (low intensity)



HV_{eV} difference between inner and outer channel (medium intensity)



HV_{eV} difference between inner and outer channel (high intensity)



Non-Quantized Heating Model

- **Hypothesis:**

- Some photons are absorbed as heat with no e/h pairs (follows Poisson process)
- High statistics => Gaussian

- **Expectation:**

- Linear increase for peak position
- Square-root increase for peak width

$$E_{\text{NTL}} = N_{\text{NTL}} B h \nu \left(1 + \frac{V_{\text{bias}}}{h \nu}\right)$$

$$E_{\text{heat}} = B h \nu f \lambda_{\text{LED}}$$

$$\sigma_{\text{heat}} = B h \nu \sqrt{f \lambda_{\text{LED}}}$$

$$E = E_{\text{NTL}} + B h \nu f \lambda_{\text{LED}}$$
$$\sigma^2 = \sigma_{\text{NTL}}^2 + B^2 (h \nu)^2 f \lambda_{\text{LED}}$$

N_{NTL} - # of e/h pairs produced

B - conversion factor from eV to ADC counts

V_{bias} - bias voltage across the crystal

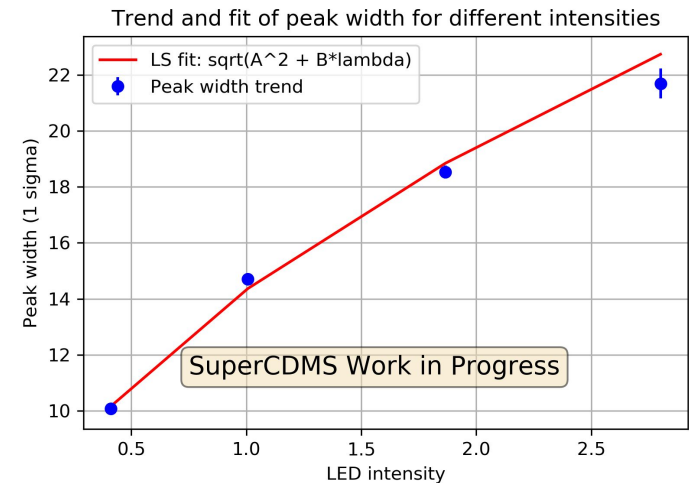
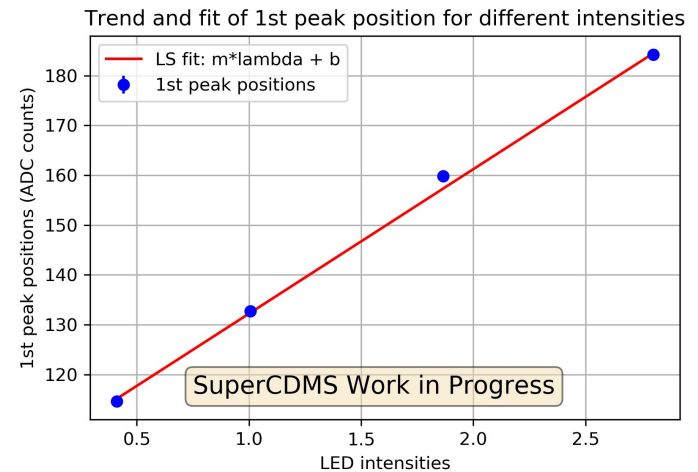
$h \nu$ - energy of a single calibration photon in eV

f - conversion factor from Poisson lambda to # of photons

Non-Quantized Heating Model Verification

- Fits for peak positions and widths resemble the data
- Compute the constants in the formulation (e.g. B, f)
- Dark Matter limit (LED intensity $\Rightarrow 0$)
- Estimation of detector resolution for Dark Matter

$$E = E_{\text{NTL}} + Bh\nu f \lambda_{\text{LED}}$$
$$\sigma^2 = \sigma_{\text{NTL}}^2 + B^2(h\nu)^2 f \lambda_{\text{LED}}$$



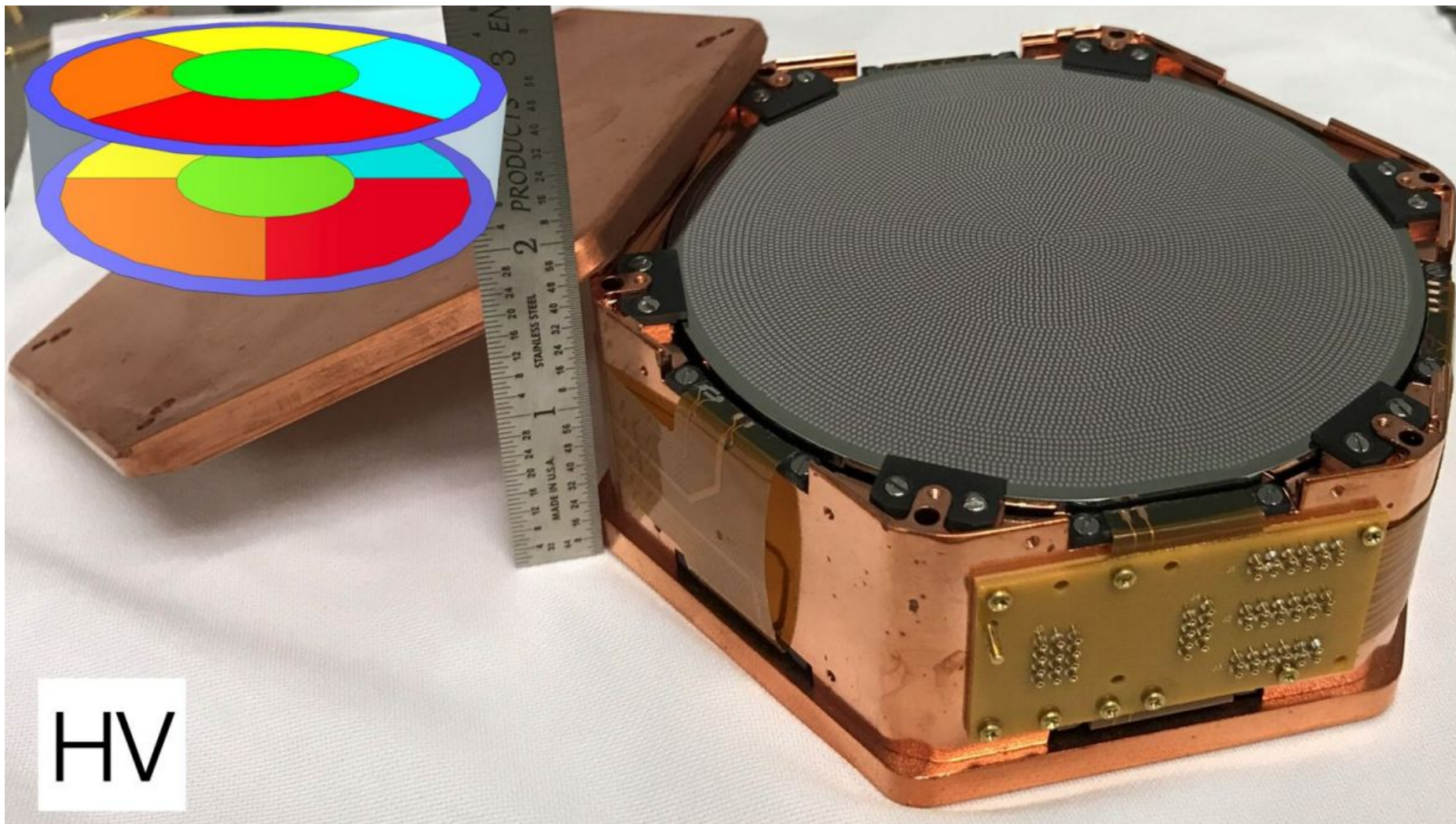
Non-Quantized Heating Sources and Future Testing

- **Hypothesis 1: Some photons are absorbed in the QET**
 - **QET: Quasi-particle trap-assisted Electrothermal feedback Transition edge sensor**
 - QET covers 50% of detector surface
 - QET has higher sensitivity to photons (QET efficiency)
 - LED was collimated at QET side
- **Hypothesis 2: Some e/h pair are trapped on the surface**
 - UV penetration depth on Si is 0.01 μm
 - Simulation suggests trapping of e/h pairs on the near surface
 - Trapped e/h pairs may be reabsorbed as heat before amplification
- **Future testing:**
 - Shining the LED on the backside of detector (no QET)
 - Using other colors and look for correlation
 - Test different polarities (e.g. +/- 150 V)
 - Current runs at TRIUMF aim at answering these questions

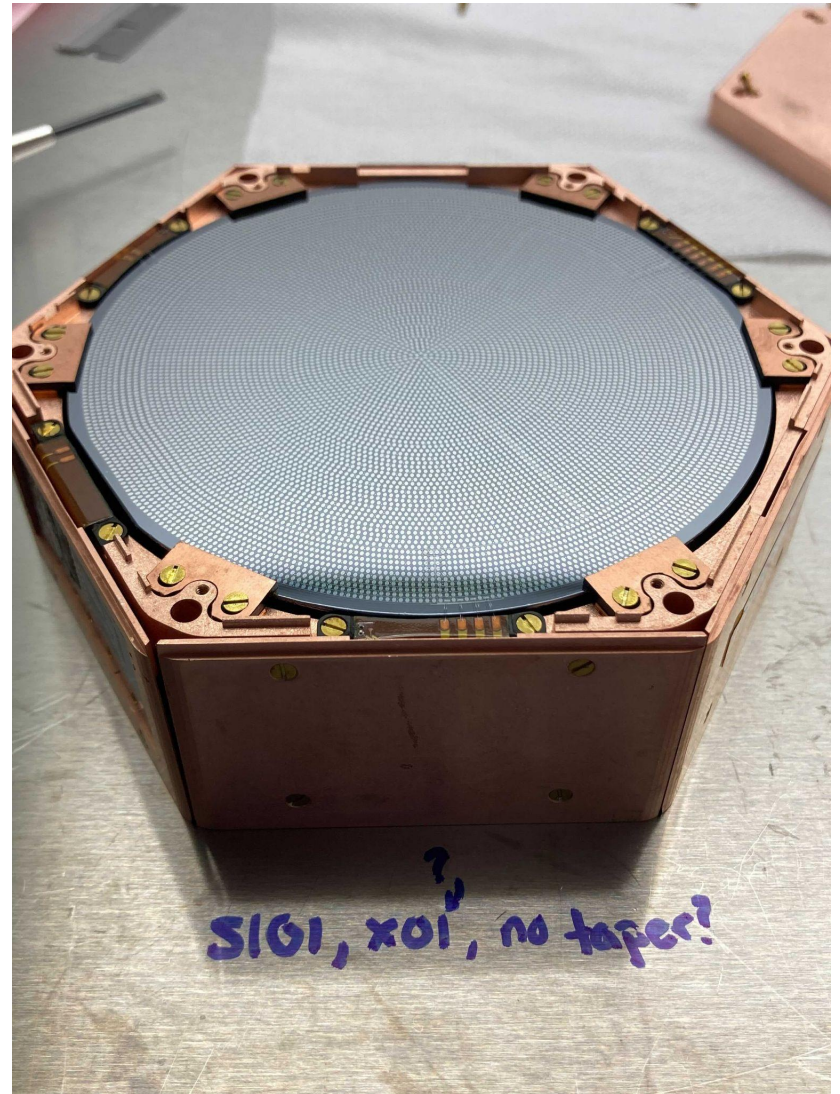
Thank you!

Backup Slides

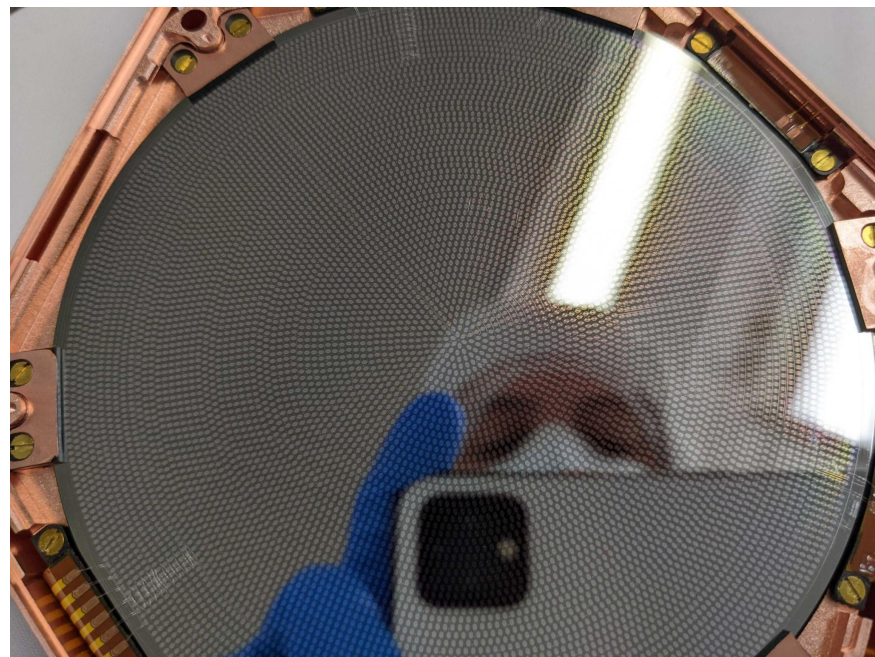
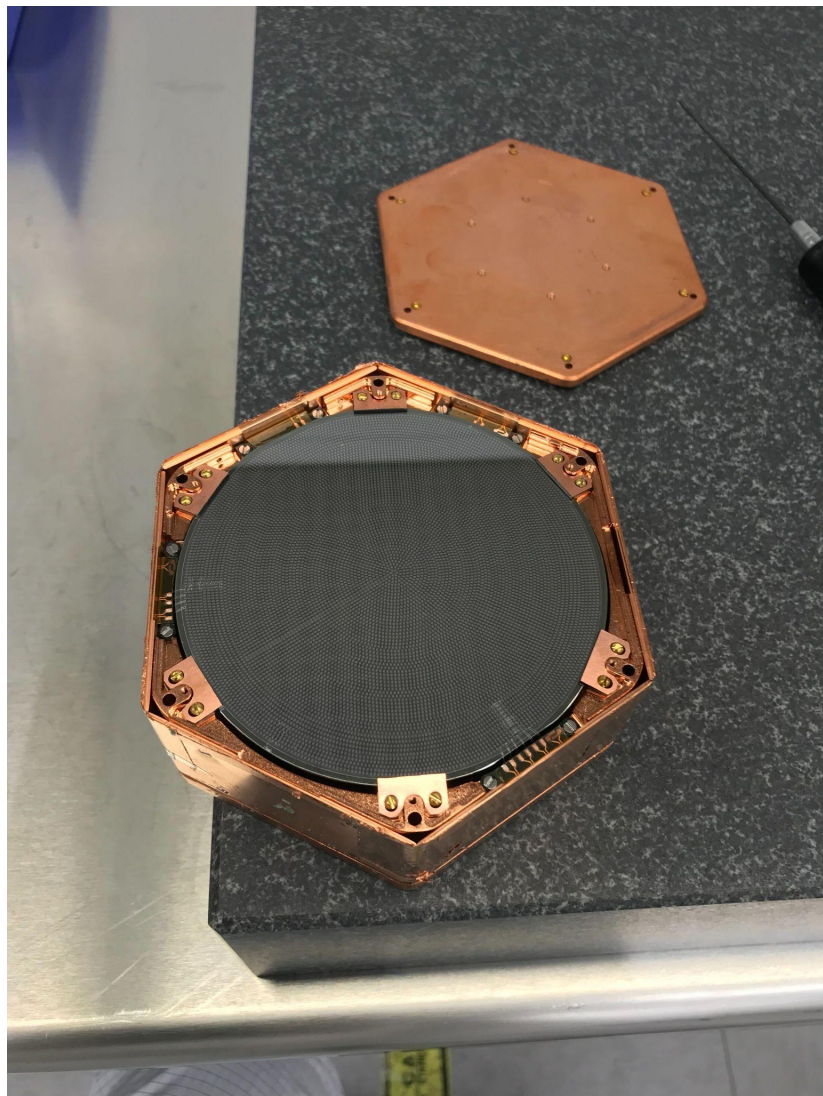
Appendix 1: HV Detectors



Appendix 2: More HV Detectors



Appendix 3: Even More HV Detectors



Appendix 4: UV LED and filter

- UV LED is 4 eV => 310 nm
- UV LED is shining through thin Al film (~20 nm). UV that makes it through the Al film passes through UV transparent glass.
- The LED is shining through small hole to centered at the inner channel of the detector.

